

# Masashi Yamashita

## List of Publications by Year in descending order

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7  
papers

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2258059

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2053705

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| # | ARTICLE  | IF  | CITATIONS |
|---|--|-----|-----------|
| 1 | Optical properties and core state of AlN $\epsilon$ BN ternary compound by <i>ab initio</i> calculations. Physica Status Solidi C: Current Topics in Solid State Physics, 2015, 12, 647-650.         | 0.8 | 1         |
| 2 | Boron addition effects on aluminum nitride fabricated by radio-frequency plasma-assisted molecular beam epitaxy. Physica Status Solidi C: Current Topics in Solid State Physics, 2007, 4, 2486-2489. | 0.8 | 5         |
| 3 | Fabrication of Aluminum Nitride Thin Film and Its Oxidation Behavior. Zairyo/Journal of the Society of Materials Science, Japan, 2006, 55, 785-789.  | 0.2 | 10        |
| 4 | Luminescent Characteristics of Undoped and Er-Doped ZnO Thin Films. Key Engineering Materials, 2006, 301, 189-192.   | 0.4 | 0         |
| 5 | Growth and Characterization of AlBN Polycrystalline Thin Film by Radio-Frequency Plasma-Assisted Molecular Beam Epitaxy. Key Engineering Materials, 2006, 301, 95-98.                                | 0.4 | 3         |
| 6 | <i>Polycrystal GaAs infrared windows</i> . , 2001, 4375, 79.   |     | 1         |
| 7 | Effects of Activation Annealing on Thermally Stimulated Current in Semi-Insulating LEC GaAs Substrates. Materials Science Forum, 1995, 196-201, 243-248.   | 0.3 | 1         |